



BAT54T /AT /CT /ST

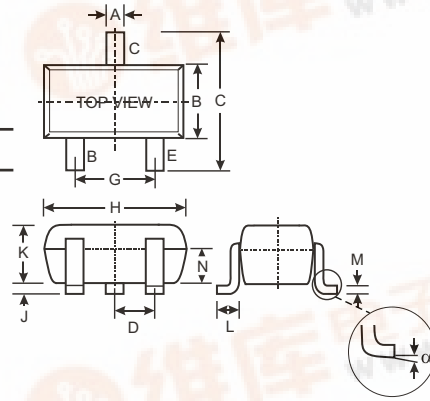
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

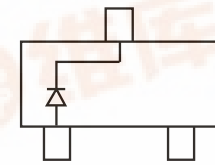
- Ultra-Small Surface Mount Package
- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection

Mechanical Data

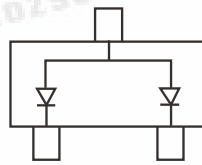
- Case: SOT-523, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams Below
- Marking: See Diagrams Below & Page 2
- Weight: 0.002 grams (approx.)
- Ordering Information, see Page 2



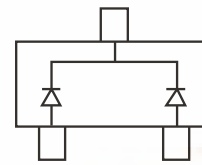
SOT-523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D			0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
	0	8	
All Dimensions in mm			



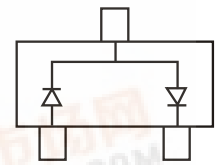
BAT54T Marking: L1



BAT54AT Marking: L2



BAT54CT Marking: L3



BAT54ST Marking: L4

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	30	V
Forward Continuous Current (Note 1)	I_{FM}	200	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Forward Surge Current @ $t < 1.0\text{s}$	I_{FSM}	600	mA
Power Dissipation (Note 1)	P_d	150	mW
Thermal Resistance, Junction to Ambient (Note 1)	R_{JA}	833	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +125	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	30			V	$I_R = 100\text{ }\mu\text{A}$
Forward Voltage (Note 2)	V_F			240 320 400 500 1000	mV	$I_F = 0.1\text{mA}$ $I_F = 1\text{mA}$ $I_F = 10\text{mA}$ $I_F = 30\text{mA}$ $I_F = 100\text{mA}$
Reverse Leakage Current (Note 2)	I_R			2.0	μA	$V_R = 25\text{V}$
Total Capacitance	C_T			10	pF	$V_R = 1.0\text{V}, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}			5.0	ns	$I_F = 10\text{mA}$ through $I_R = 10\text{mA}$ to $I_R = 1.0\text{mA}$, $R_L = 100\text{ }\Omega$

- Notes:
- Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 - Short duration test pulse used to minimize self-heating effect.

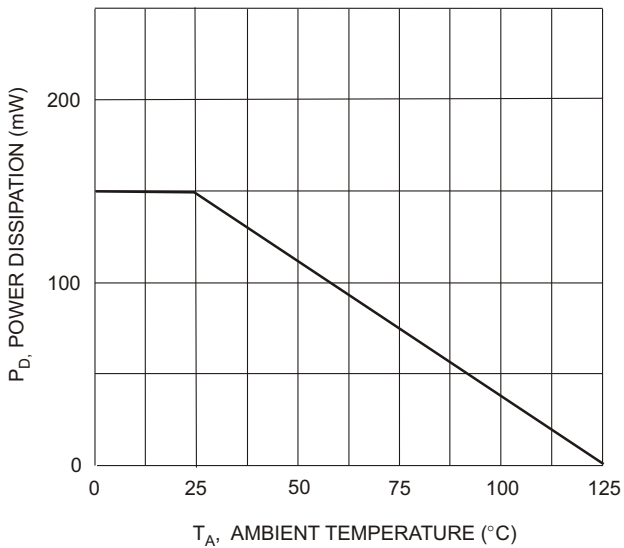


Fig. 1 Power Derating Curve

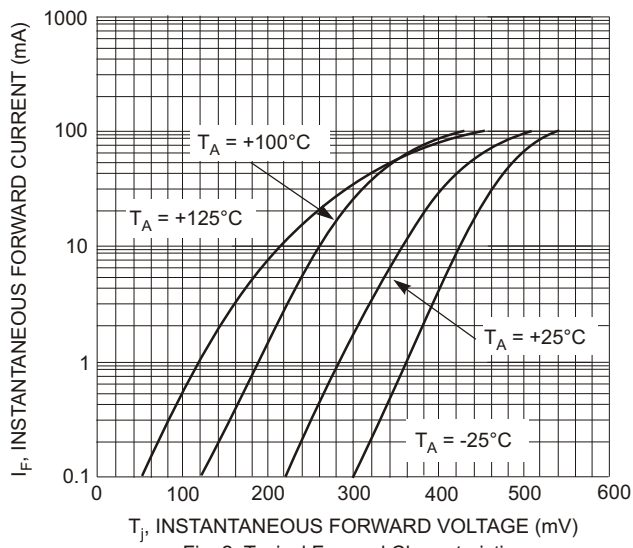


Fig. 2, Typical Forward Characteristics

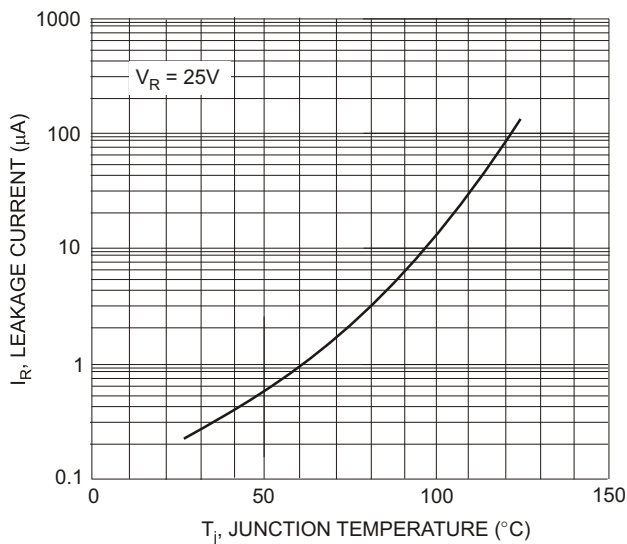


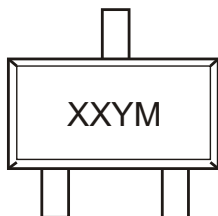
Fig. 3, Typical Reverse Characteristics

Ordering Information (Note 3)

Device	Packaging	Shipping
BAT54T-7	SOT-523	3000/Tape & Reel
BAT54AT-7	SOT-523	3000/Tape & Reel
BAT54CT-7	SOT-523	3000/Tape & Reel
BAT54ST-7	SOT-523	3000/Tape & Reel

Notes: 3. For Packaging Details: go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



XX = Product Type Marking Code (See Page 1, e.g. L1 = BAT54T)
 YM = Date Code Marking
 Y = Year (ex: N = 2002)
 M = Month (ex: 9 = September)

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D